



M T B F

(E I A J R C R - 9 1 0 2)

Model	LEA50F-9
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No.	P a r t s		Q' ty of Device	Failure rate [10 ⁻⁶ /H]	Reference
1	I C	Monolithic	3	0.1060	
2		Hybrid	0	0.0000	
3	Transistors		6	0.3003	
4	Diodes		19	0.3850	
5	LED•Optocouplers		2	0.1400	
6	Resistors		84	0.4606	
7	Capacitors		31	0.3460	
8	Transformer•Choke Coil		8	0.1219	
9	Connectors		368	0.1908	
10	Others		5	0.0880	
Total Failure Rate [10 ⁻⁶ /H]				2.1386	

M T B F	[H]	468,000
Ambient Temperature	[°C]	—
Load Factor	[%]	—